

Is Now Part of



# **ON Semiconductor**®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor dates sheds, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheds and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use on similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any lay bed ON Semiconductor and its officers, employees, ween if such claim alleges that ON Semiconductor was negligent regarding the d



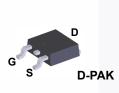
### FCD7N60 N-Channel SuperFET<sup>®</sup> MOSFET 600 V, 7 A, 600 mΩ

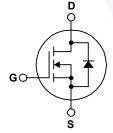
### Features

- 650 V @ T<sub>.1</sub> = 150°C
- Typ. R<sub>DS(on)</sub> = 530 mΩ
- Ultra Low Gate Charge (Typ. Q<sub>q</sub> = 23 nC)
- Low Effective Output Capacitance (Typ. C<sub>oss(eff.)</sub> = 60 pF)
- 100% Avalanche Tested
- RoHS Compliant

### Application

- LCD / LED TV and Monitor
- Lighting
- Solar Inverter
- AC-DC Power Supply





 $SuperFET^{\textcircled{M}}MOSFET$  is Fairchild Semiconductor's first generation of high voltage super-junction (SJ) MOSFET family that is

utilizing charge balance technology for outstanding low on-

resistance and lower gate charge performance. This technology

is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Con-

sequently, SuperFET MOSFET is very suitable for the switching

power applications such as PFC, server/telecom power, FPD

TV power, ATX power and industrial power applications.

Description

### MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter			FCD7N60TM / FCD7N60TM_WS	Unit V
V <sub>DSS</sub> Drain to Source Voltage			600		
ID	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		7	
	Drain Current	- Continuous (T <sub>C</sub> = 100 <sup>o</sup> C)		4.4	- A
I <sub>DM</sub>	Drain Current	- Pulsed	- Pulsed (Note 1)		Α
V <sub>GSS</sub>	Gate to Source Voltage			±30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy		(Note 2)	230	mJ
I <sub>AR</sub>	Avalanche Current		(Note 1)	7	Α
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	8.3	mJ
dv/dt	Peak Diode Recovery dv/dt (Note:		(Note 3)	20	V/ns
P <sub>D</sub>	Power Dissipation	(T <sub>C</sub> = 25°C)		83	W
		- Derate Above 25°C		0.67	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		econds	300	°C

### **Thermal Characteristics**

Symbol	Parameter	FCD7N60TM / FCD7N60TM_WS	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.5	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient, Max.	83	0.00

December 2013

FCD7N60
– N-Channe
I SuperFET®
MOSFET

FCD7N60TM FCD7N60 D-		Top Mark	Packag	ge	Packing Method	Reel Size	Тар	e Width	Qua	ntity	
		FCD7N60	D-PAK	<	Tape and Reel	330 mm	1	6 mm	2500	2500 units	
		D-PAł	AK Tape and Reel 330 mm		330 mm	16 mm		2500 units			
Floctrica	l Chara	cteristics T <sub>c</sub> = 25		othe	nviso notod				-		
Symbol		Parameter	C uniess		Test Conditio	ons	Min.	Тур.	Max.	Unit	
Off Charac	teristics							.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			
				Vc	<sub>is</sub> = 0 V, I <sub>D</sub> = 250 μA	T <sub>C</sub> = 25 <sup>o</sup> C	600	-	-	V	
BV <sub>DSS</sub> Drain to Source Breakdown Voltage		age	$V_{GS} = 0 V, I_D = 250 \mu A, T_C = 150^{\circ}C$		-	650	-	V			
ΔΒV <sub>DSS</sub> / ΔΤ.I	Breakdown Voltage Temperature			$I_D = 250 \ \mu\text{A}, \text{Referenced to } 25^{\circ}\text{C}$		-	0.6	-	V/°C		
BV <sub>DS</sub>	Drain to S Voltage	Source Avalanche Breal	kdown	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 7.0 A		-	700	-	V		
				VD	$v_{\rm S}$ = 600 V, V <sub>GS</sub> = 0 V	'	-	-	1	μA	
IDSS	Zero Gale	ero Gate Voltage Drain Current		V <sub>DS</sub> = 480 V, T <sub>C</sub> = 125 <sup>o</sup> C		-	-	10	μΑ		
I <sub>GSS</sub>	Gate to B	ody Leakage Current		$V_{GS}$ = ±30 V, $V_{DS}$ = 0 V		-	-	±100	nA		
On Charac	teristics										
V <sub>GS(th)</sub>	Gate Threshold Voltage			$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$		3.0	-	5.0	V		
R <sub>DS(on)</sub>	Static Drain to Source On Resistance			$_{SS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$		-	0.53	0.6	Ω		
9 <sub>FS</sub>	Forward 7	Forward Transconductance		V <sub>DS</sub> = 40 V, I <sub>D</sub> = 3.5 A		-	6	-	S		
Dynamic C	haracter	istics									
C <sub>iss</sub>	Input Cap	acitance		V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz		-	710	920	pF		
C <sub>oss</sub>	Output Ca	apacitance				-	380	500	pF		
C <sub>rss</sub>	Reverse 7	Fransfer Capacitance				-	34	-	pF		
C <sub>oss</sub>	Output Capacitance		$V_{DS}$ = 480 V, $V_{GS}$ = 0 V, f = 1 MHz		-	22	29	pF			
C <sub>oss(eff.)</sub>	Effective Output Capacitance			$V_{DS}$ = 0 V to 400 V, $V_{GS}$ = 0 V		-	60	-	pF		
Switching	Characte	eristics									
t <sub>d(on)</sub>	Turn-On E	Delay Time						35	80	ns	
t <sub>r</sub>	Turn-On Rise Time Turn-Off Delay Time		V <sub>DD</sub> = 300 V, I <sub>D</sub> = 7.0 A,		-	55	120	ns			
t <sub>d(off)</sub>			Ve	$V_{GS}$ = 10 V , $R_{G}$ = 25 $\Omega$		-	75	160	ns		
t <sub>f</sub>	Turn-Off F	all Time		(Note 4)		7-	32	75	ns		
Q <sub>g(tot)</sub>	Total Gate	Charge at 10V		V	<sub>os</sub> = 480 V, I <sub>D</sub> = 7.0 A	. ,	-	23	30	nC	
Q <sub>gs</sub>		ource Gate Charge	-		$V_{\rm GS} = 480$ V, $T_{\rm D} = 7.0$ A, $V_{\rm GS} = 10$ V		-	4.2	5.5	nC	
Q <sub>gd</sub>	Gate to D	ain "Miller" Charge		(Note 4)		-	11.5	-	nC		
	ce Diode	Characteristics									
I <sub>S</sub>	Maximum Continuous Drain to Source Diode Forward Current				-	-	7	A			
	Maximum Pulsed Drain to Source Diode Fo				-		21	A			
I <sub>SM</sub> V <sub>SD</sub>		ource Diode Forward V				-	· .	1.4	V		
		Recovery Time	onugo	$V_{GS} = 0 V, I_{SD} = 7.0 A$ $V_{GS} = 0 V, I_{SD} = 7.0 A,$ $dI_F/dt = 100 A/\mu s$				360	-		
t <sub>rr</sub>	Reverse F	kecoverv Lime							ns		

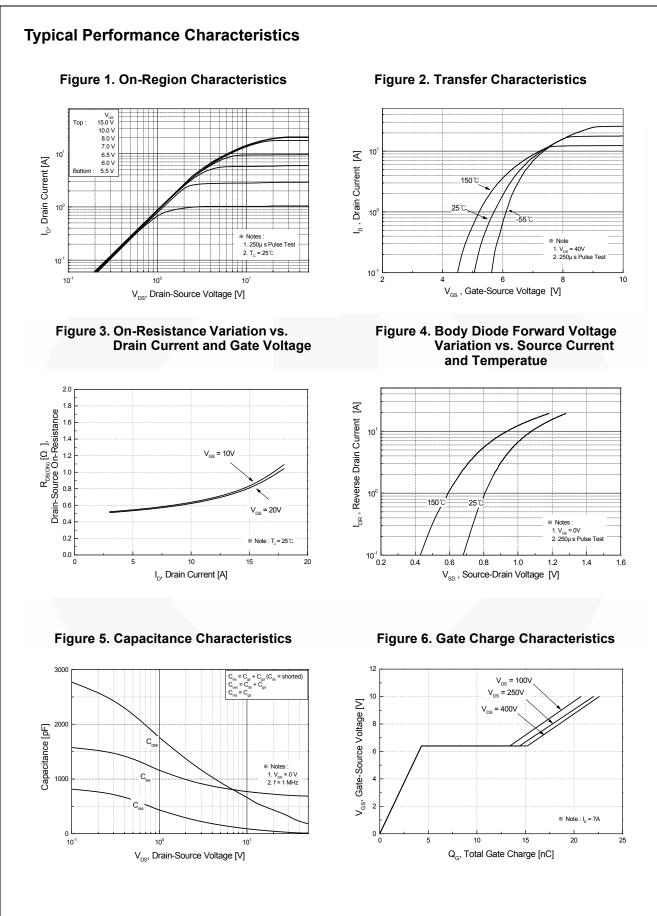
Notes:

1. Repetitive rating: pulse-width limited by maximum junction temperature.

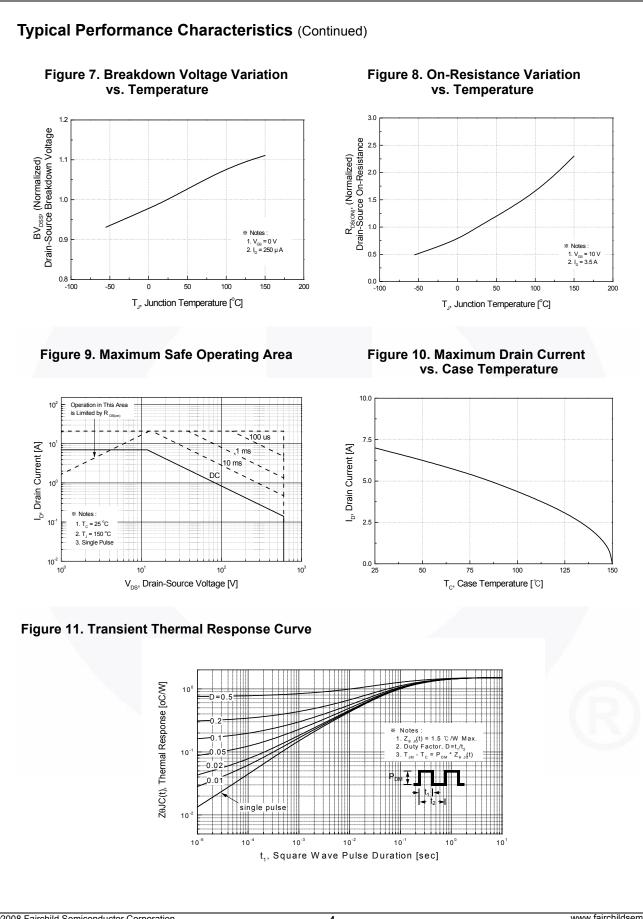
2.  $I_{AS}$  = 3.5 A,  $V_{DD}$  = 50 V,  $R_{G}$  = 25  $\Omega,$  starting  $T_{J}$  = 25°C.

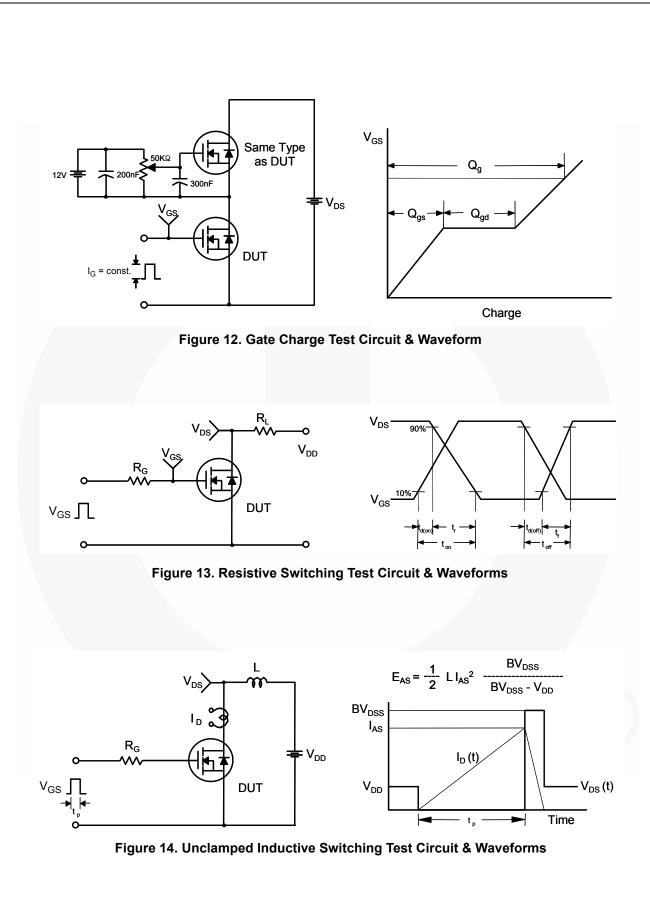
3.  $I_{SD} \le$  7 A, di/dt  $\le$  200 A/µs,  $V_{DD} \le$  BV<sub>DSS</sub>, starting T<sub>J</sub> = 25°C.

4. Essentially independent of operating temperature typical characteristics.

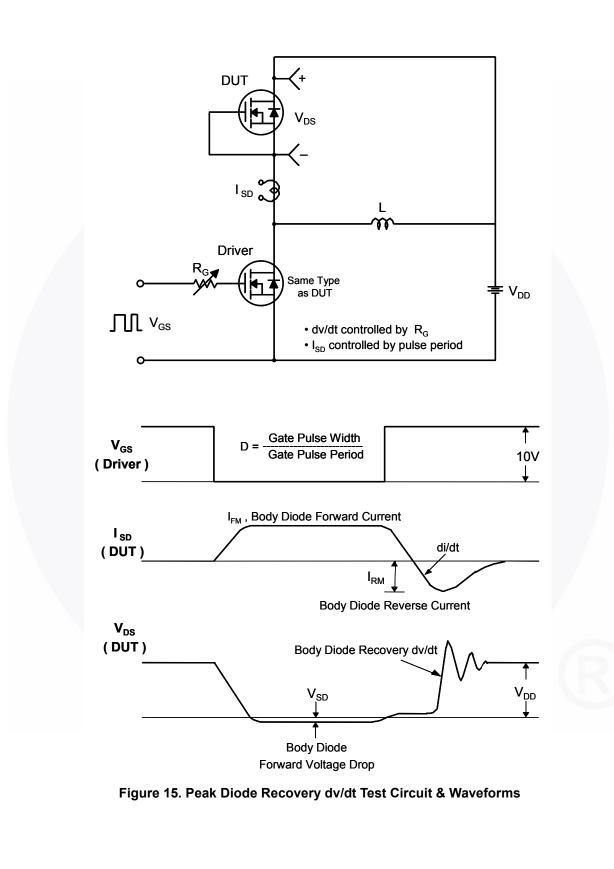


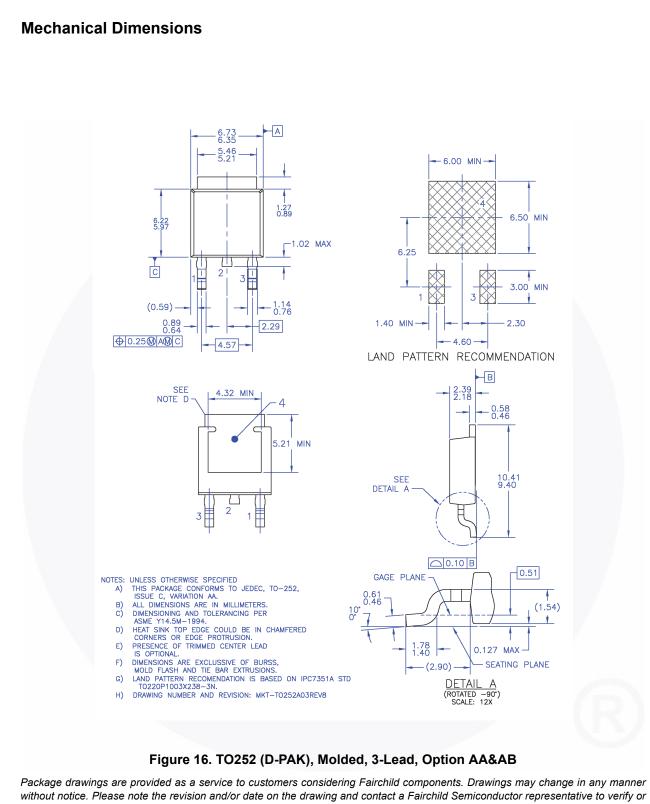
## ©2008 Fairchild Semiconductor Corporation FCD7N60 Rev. C1





FCD7N60 — N-Channel SuperFET<sup>®</sup> MOSFET





FCD7N60 — N-Channel SuperFET<sup>®</sup> MOSFET

obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

http://www.fairchildsemi.com/package/packageDetails.html?id=PN\_TT252-003



SEMICONDUCTOR

#### TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™	F-PFS™	
AX-CAP <sup>®</sup> *	FRFET®	
BitSiC™	Global Power Resource <sup>SM</sup>	PowerTrench <sup>®</sup>
Build it Now™	GreenBridge™	PowerXS™
CorePLUS™	Green FPS™	Programmable Active Droop™
CorePOWER™	Green FPS™ e-Series™	QFET®
CROSSVOLT™	Gmax™	QS™
CTL™	GTO™	Quiet Series™
Current Transfer Logic™	IntelliMAX™	RapidConfigure™
DEUXPEED®	ISOPLANAR™	
Dual Cool™	Marking Small Speakers Sound Louder	
EcoSPARK®	and Better™	Saving our world, 1mW/W/kW at a time™
EfficentMax™	MegaBuck™	SignalWise™
ESBC™	MICROCOUPLER™	SmartMax™
R	MicroFET™	SMART START™
	MicroPak™ MicroPako™	Solutions for Your Success™ SPM <sup>®</sup>
Fairchild®	MicroPak2™	
Fairchild Semiconductor®	MillerDrive™ MotionMax™	STEALTH™ SuperFET <sup>®</sup>
FACT Quiet Series™	mWSaver®	SuperSOT™-3
FACT®	OptoHiT™	SuperSOT™-5
FAST®	OPTOLOGIC®	SuperSOT™-8
FastvCore™	OPTOPLANAR®	SupreMOS <sup>®</sup>
FETBench™ FPS™		SyncFET™
1 - 3		-,

\*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

Sync-Lock™ SYSTEM<sup>®\*</sup> GENERAL

TinyBoost

TinyBuck® TinyCalc™ TinvLogic® TINYOPTO™

TinvPower™

TinyPWM™

TinyWire™

TranSiC™

Ultra FRFET™

VisualMax™

VoltagePlus™

UHC®

VCX™

XS™

UniFFT™

TriFault Detect™

TRUECURRENT®\* µSerDes™

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### **PRODUCT STATUS DEFINITIONS** Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC